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Magnetic damping in polycrystalline Fe-V thin film alloys

Monika Arora¹, Erna K. Delczeg-Czirjak², Grant Riley¹-³, T.J. Silva¹, Hans T. Nembach¹-⁴, Olle Eriksson²-⁵, Justin M Shaw¹*

¹Quantum Electromagnetics Division, National Institute of Standards and Technology, Boulder, CO 80305 USA
²Department of Physics and Astronomy, University Uppsala, S-75120 Uppsala, Sweden
³Center for Memory and Recording Research, University of California-San Diego, La Jolla, CA 92093 USA
⁴JILA, University of Colorado, Boulder, Colorado 80309, USA
⁵School of Science and Technology, Örebro University, SE-701 82 Örebro, Sweden

* corresponding author: justin.shaw@nist.gov

ABSTRACT

We report on the magnetic damping properties of polycrystalline Fe-V alloy thin films that were deposited at room temperature. By varying the concentration of V in the alloy, the saturation magnetization can be adjusted from that of Fe to near zero. We show that an exceptionally low values of the damping parameter can be maintained over the majority of this range with a minimum of the damping at approximately 15-20% V concentration. Such a minimum is qualitatively reproduced with ab initio calculations of the damping parameter although at a concentration closer to 10% V. The measured intrinsic damping has a minimum value of $(1.53 \pm 0.08) \times 10^{-3}$ which is approximately a factor of 3 higher than our calculated value of $0.48 \times 10^{-3}$. From first principles theory, we outline the factors that are mainly responsible for the trend of the damping parameter in these alloys. In particular, the band structure and resulting damping mechanism is shown to change at V concentrations greater than approximately 35% V content.

INTRODUCTION

Damping of magnetization dynamics has become an important topic for applications in magnetic memories, data storage, magnonics and spin-logic. [1–8] The strength of the damping has a large impact on the speed and energy required to switch or operate such devices. Ideally, the damping parameter would be a parameter that could be independently optimized for a particular application. However, the intrinsic damping can be challenging to engineer since it is largely driven by the details of the bandstructure. [9–17] In particular, it has been shown that the density of states at the Fermi energy $n(E_F)$ is a dominant factor in determining the damping of a metal or half-metal, where a proportionality between damping and $n(E_F)$ was found. [18–23] However, modifying a material’s bandstructure through, for example, strain engineering, crystalline phase or alloying the material with other elements may result in undesirable effects on other magnetic properties such as saturation magnetization and magnetic anisotropy. Complicating matters, many extrinsic factors also contribute to the damping such as spin-pumping, eddy currents, radiative damping, and two magnon scattering. [24–33]

For many applications, an extremely low value of the damping parameter $\alpha$ is desired. [4–8] While this can routinely be achieved in insulating materials such as magnetic garnets and ferrites [34–43], this is more challenging in conductors due to the presence of conduction electrons which leads to significant magnon-electron scattering contributions to the damping. [44,45] It was recently shown that Co-Fe alloys can exhibit exceptionally low values of the damping parameter at certain concentrations.
due to a sharp minimum in $n(E_f)$. [18] However, this material has an exceptionally high value of the saturation magnetization $\mu_0M_s$, which can be as high as 2.4 T. Such high values of $\mu_0M_s$ can be useful for many applications in magnonics since the high $\mu_0M_s$ yields high magnon velocities and better coupling for transduction. [46] However, for other applications, a material with such a high value of $\mu_0M_s$ is prohibitive. For example, the critical current for a spin transfer torque magnetic random-access memory cell is proportional to both $\mu_0M_s$ and $\alpha$. [47] Thus, any benefit gained from a reduced $\alpha$ may be offset by the higher $\mu_0M_s$.

As a consequence, it is often desired to have materials that exhibit exceptionally low magnetic damping while simultaneously having low values of $\mu_0M_s$. Many half-metallic systems can fulfill this requirement, but fabrication requires high temperatures and/or epitaxial growth. [12,13,17,21–23,48–51] One solution may reside in metallic alloys based on Fe and V. Initial calculations by Mankovsky et al., indeed show calculated damping values below 0.001. [52] In addition, since elemental V is not ferromagnetic and the Fe-V alloys adhere to the Slater-Pauling behavior, $\mu_0M_s$ can be continuously adjusted from that of pure Fe ($\mu_0M_s = 2.1$ T) to a value that vanishes ($\mu_0M_s = 0$) near 67 % V. Previous work has shown low values of damping in this system, but do not reach the low values predicted by theory. [53–56] More recently, a minimum in the damping parameter approaching 0.001 was found at a composition of $\sim 25$% V. [57] However, these studies were mostly limited to single crystalline, epitaxial films. For most applications, epitaxial growth is not possible, either due to lack of a single crystalline template (back end processing), thermal budget considerations, and/or throughput considerations. While distinction between single crystal and polycrystalline systems initially appears to be a formality, the additional disorder found in the polycrystalline case can affect the spin scattering rates. This has the potential to have significant impact on the damping parameter, either increasing it or decreasing it depending on the dominate scattering mechanism of the system. [10,14,58,59]

In this work, we address the question about whether the low damping properties can be maintained or possibly improved in room-temperature deposited polycrystalline films suitable for CMOS integration. We compare our results to $ab$ initio calculations of the damping parameter. Furthermore, we confirm that the density of states at the Fermi energy largely drives the damping properties in this system. However, due to significant band broadening, this proportionality is not strictly maintained over all compositions.

**EXPERIMENT**

Fe$_{1-x}$V$_x$ alloys were deposited by co-sputtering from a pure Fe and pure V target with an Ar plasma at a pressure of approximately 0.6 Pa (0.5 mTorr). Rates were calibrated and periodically monitored using x-ray reflectometry. We estimate an upper bound on the uncertainty of the deposition rates to be 5 %. The base pressure of the deposition chamber was approximately $1 \times 10^{-7}$ Pa ($1 \times 10^{-3}$ Torr). For the majority of samples, the Fe$_{1-x}$V$_x$ layer thickness was fixed at 10 nm. However, for a select subset of alloy concentrations, we deposited a thickness series in order to isolate interfacial properties. To promote good growth and protection from oxidation, a 3 Ta / 5 Cu seed layer and 5 Cu / 3 Ta capping layer was used. X-ray diffraction (XRD) (not shown) reveals a strong [110] texture with a body centered cubic (bcc) crystalline structure, although we will address the possibility of the presence of a more ordered B2 structure later.

Magnetometry was performed by use of a commercial superconducting quantum interference device (SQUID) magnetometer. Here, samples were precisely diced into 6 mm x 6 mm pieces to enable
accurate knowledge of the volume of the Fe\textsubscript{(1-x)}V\textsubscript{x} layer and therefore determination of the saturation magnetization $M_s$.

Broadband ferromagnetic resonance spectroscopy was performed on samples that were also diced into 6 mm x 6 mm in size. Sample were spin coated with poly methyl methacrylate (PMMA) to prevent electrical shorting before being placed face down on a co-planar waveguide with a center conductor of 100 µm. We used a superconducting magnet to apply magnetic fields of up to $\mu_0H = 3$ T perpendicular to the sample surface. As the magnetic field was swept through the FMR condition, the transmission $S_21$ through the CPW was measured by use of a vector network analyzer capable of applying microwaves with a frequency range of 1 – 70 GHz. An example of the measured real and imaginary $S_21$ parameter is given in the inset of Fig. 1 for a 20 % V sample measured at 30 GHz. These spectra are fit to the dynamic susceptibility as outlines in Ref [60] to determine the resonance field $H_{res}$ and linewidth $\Delta H$ for a given frequency $f$. As this data is acquired over a large range of frequency, we generate plots of the $H_{res}$ and $\Delta H$ as functions of $f$, examples of which are shown in Figs. 1(a) and 1(b), respectively. Also included in Fig. 1(a) are the fits to the following equation that is used to determine the perpendicular anisotropy and spectroscopic g-factor.

$$f = \frac{\mu_0\mu_B g}{2\pi\hbar} (H_{res} - M_{eff})$$  

where $g$ is the spectroscopic g-factor, $\mu_0$ is the permeability of free space, $\mu_B$ is the Bohr magneton, and $\hbar$ is the reduced Planck’s constant. The effective magnetization $M_{eff}$ is defined as $M_{eff} = M_s - H_k$, where $H_k$ is the perpendicular anisotropy field. Similarly, the magnetic damping parameter $\alpha$ and inhomogeneous contribution to the linewidth $\Delta H_0$ are determined by fits of the following equation to the frequency dependence of the linewidth $\Delta H$.

Figure 1. (a) Resonance field and (b) linewidth versus frequency for several compositions of 10 nm thick FeV films. The inset is an example of the VNA-FMR spectrum and fits of the susceptibility to the data for the 20 % V sample at 30 GHz.
\[ \Delta H = \Delta H_0 + \frac{4\pi\alpha}{\gamma\mu_0} f \]

where \( \gamma = (\mu g)/\hbar \). The perpendicular geometry was intentionally chosen to minimize contributions to the linewidth from 2-magnon scattering. [27–32] In addition, all samples greater than 5 nm in thickness were measured using a 60 \( \mu \)m thick sapphire spacer placed between the sample and the waveguide to minimize any radiative damping contributions. [33] Calculations of the radiative damping contribution indicate that it is negligible within these measurement conditions.

**DETAILS OF THE CALCULATION**

The electronic structure is obtained solving the Kohn-Sham equations as implemented in the spin-polarized relativistic Korringa-Kohn-Rostoker (SPR-KKR) code. [61] The chemical disorder was treated within the coherent potential approximation (CPA). [62,63] The Perdew-Burke-Ernzerhof [64] exchange-correlation functional was employed. Bandstructures represented by the Bloch spectral functions (BSF) are calculated within the scalar relativistic approximation as presented by Ebert et al. [65]

To obtain the damping parameter, the Dirac equation was solved within the atomic sphere approximation. The angular momentum cutoff of \( I_{\text{max}} = 4 \) was used in the multiple scattering expansion. A \( k \)-point grid consisting of \( \approx 1600 \) points in the irreducible Brillouin zone was employed for the self-consistent calculations, and more than 1,500,000 for the damping calculations. The damping parameter, \( \alpha \), evaluated at 300 K was calculated via the linear response theory. [9] An alloy analogy model within CPA was considered in order to include the temperature effects in the scattering process of electrons with respect to atomic displacement. [66] The “scattering-in” term of the Boltzmann equations was taken into account via vertex corrections. [67] All calculations are done for the experimental lattice parameters obtained from the Pearson crystal database, [68] that are specifically: 0.2856 nm for Fe [69], 0.2878 nm for Fe\(_{0.6}\)V\(_{0.4}\) [70], 0.2892 nm for Fe\(_{0.4}\)V\(_{0.6}\) [71], 0.2900 nm for Fe\(_{0.3}\)V\(_{0.7}\) [72], 0.2905 nm for Fe\(_{0.65}\)V\(_{0.35}\) [73], 0.2911 nm for Fe\(_{0.55}\)V\(_{0.45}\) [74], 0.2916 nm for Fe\(_{0.3}\)V\(_{0.7}\) [75] bcc alloys and 0.291 nm for FeV in the B\(_2\) (CsCl) structure. [75] Value for Fe\(_{0.6}\)V\(_{0.4}\) is interpolated from the Fe\(_{0.55}\)V\(_{0.45}\) and Fe\(_{0.65}\)V\(_{0.35}\) data. Debye temperature (\( T_D \)) of FeV alloys for the damping calculations are extrapolated from the Fe and V room temperature experimental values. [76] It is important to point out that these lattice constants are room temperature values, which will partially take some of the thermal effects (i.e., thermal expansion) into account. As a check, the lattice constant for the Fe\(_{50}\)V\(_{50}\) sample was verified to be within 1 % of the tabulated bulk values. Such a variation of the lattice constant will cause a change in the calculated damping constant of less than 10 %. As we will later see, this is outside of any meaningful range.

**RESULTS**

Figure 2 shows that the saturation magnetization \( \mu_0 M_s \) and effective magnetization \( \mu_0 M_{\text{eff}} \) decrease in an almost linear fashion as the V content increases, which is consistent with previous reports. [54,56,57,77] This is expected from the simplified band-filling Slater-Pauling model. This model predicts that the magnetization should vanish at a concentration of 67 % V. Indeed, even more thorough calculations of magnetic moment show little deviation from these simpler models. [77] Projecting our data to higher V concentrations shows that the magnetization will vanish at approximately 60 % V. This small deviation could be a result of the limitation of the Slater-Pauling model, finite temperature effects,
errors in the deposition rates/stoichiometry, and/or interfacial effects. However, two previous reports also show a vanishing value of $\mu_0 M_s$ at 60 % V. [54,77] From an applications standpoint, the data in Fig. 2 is desired since it shows the straightforward ability to tune both $\mu_0 M_s$ and $\mu_0 M_{\text{eff}}$ over a large range of values.

Unlike the trends in $M_s$, Fig. 3(a) shows that the g-factor exhibits little variation as a function of composition – exhibiting only a small increase from $g \approx 2.08$ to $g \approx 2.10$ from pure Fe to 10 % V, which is consistent with what was found in epitaxial films. [57] However, our data also exhibits significant scatter. The scatter was reduced by use of the asymptotic analysis to the determination of the g-factor. [78] However, given the high value of saturation magnetization and limited magnetic field, we were unable to apply this method to the pure Fe sample. We include a value of the g-factor for pure Fe taken from Schoen et al. to provide an additional data point. [79] Even with the scatter of the data, these results show that the orbital moment and therefore the spin-orbit interaction do not vary significantly as a function of concentration. This is not surprising given the fact that Fe and V have similar atomic numbers at 26 and 23, respectively.

The damping parameter for the 10 nm thick layers as a function of V concentration are shown as the black data points in Fig. 3(b). The data show a minimum value in the vicinity of 15 % V. However, even at a thickness of 10 nm, there will be a significant spin-pumping contribution to the damping. [24,80,25,81] To quantitatively account for spin-pumping effects, we measured the damping as a function of thickness for samples with V concentration of 0%, 10 %, 20 %, 35 %, and 50 %. Figure 3(c) shows an example of damping versus the inverse thickness for 20 % V. As expected from spin-pumping theory, the data exhibits a linear behavior versus inverse thickness. The y-intercept corresponds to the value of the damping parameter with the spin-pumping contribution removed, whereas the slope is equal to \((g \mu_s g_{\uparrow\downarrow_{\text{eff}}})/(4\pi M_s)\) where \(g_{\uparrow\downarrow_{\text{eff}}}\) is the effective real part of the spin-mixing conductance. Since there are no other known contributions to the damping, these values obtained from the y-intercepts are identified as the intrinsic damping of the material and is plotted in Fig. 3(b) as the blue data. These data also show a minimum value, but it is shifted to a higher V concentration of approximately 20 % V relative to the uncorrected data for the 10 nm samples. This trend can be understood from the fact that the spin-pumping contribution is proportional to \(1 / M_s\). Combined with the variation of \(g_{\uparrow\downarrow_{\text{eff}}}\) as a function of concentration, the spin-pumping contribution should increase substantially with the increased V concentration. This is explicitly shown in Fig. 3(d) where both $g_{\uparrow\downarrow_{\text{eff}}}$ and the ratio of $g_{\uparrow\downarrow_{\text{eff}}}/\mu_0 M_s$ are plotted. The latter quantity indicates how the spin-pumping contribution will vary with composition since it is proportional to that contribution for a given thickness.

![Figure 2. Saturation magnetization and effective magnetization versus the V concentration.](image-url)
Figure 3. (a) Spectroscopic g-factor versus V concentration for the 10 nm thick films. Gray data point is taken from Ref. [79], (b) Damping parameter for the 10 nm films (black square), intrinsic values (blue circle) and ab-initio calculated values (red triangles) versus the V concentration. The open triangle represent calculations with increased amounts of B2 order. (c) An example of the dependence of the damping parameter on inverse thickness used to account for the spin-pumping contribution for the 20 % V samples. The red line is a linear fit through the data. (d) Plot of the effective spin-mixing conductance and effective spin-mixing conductance divided by the saturation magnetization versus the V concentration of the alloy.

AB INITIO CALCULATIONS

Also included in Fig. 3(b) are the ab-initio calculated values of the damping parameter (red filled triangles). These values should be compared to the intrinsic contribution to the damping (blue curve in Fig.3b) and two distinct features stand out in this comparison. First of all, we note that for lower V concentrations (up to 35 %) the trend of the calculated damping parameter is consistent with the observed values, albeit with an approximately factor of two or more reduced value. Secondly, for higher V concentrations (larger than 35 %) the trend in the experimental data, which shows a sharp increase in the damping with higher V concentration, is not at all captured by theory. We will return to the latter aspect below, but note first that the damping parameters presented here are in good agreement with those shown in Ref. [52] calculated for 300 K. Secondly, we note that the reproduction of extremely
low values of the damping parameter, as is the case in this investigation, is notoriously difficult for ab-initio theory. [15,52]

In order to further analyze the trend in the calculated damping parameter we compare the calculated damping parameter (red filled triangles) with the density of states at the Fermi level, $n(E_F)$ (black open circles) in Fig. 4. Hence, Fig. 4 compares two sets of theoretical data. It can be seen that the damping parameter follows that of the $n(E_F)$ up to approximately 35 % V, where the damping is seen to increase more rapidly relative to the DOS at the Fermi energy. A microscopic explanation to this behavior can be found from a detailed analysis of the electronic structure, as represented by the Bloch spectral functions (BSFs) in Fig. 5. For lower V concentrations the energy bands (as represented by the BSF) are relatively well defined, without any major change between alloys with different V concentrations. However, at approximately 35 % V there is a distinct change in the BSF. This is illustrated in Fig. 5, where we show BSFs for spin-up and spin down states, for 30 % (upper panels) and 50 % (lower panels) V concentrations. First it should be noted that for the spin-down states, the energy dispersion has very sharp, band like features, that are similar for both alloy concentrations. This is due to the similar scattering properties of spin-down Fe and V states in the bcc structure. Note that for the spin-down states the BSFs are particularly sharp for states around the Fermi energy [$E_F = E(k) = 0$], which allows to identify sharp features of the Fermi surface for these states.

In contrast, the situation is drastically different for the spin-up states. Figure 5 shows that most features in the spin-up state are considerably more smeared out or broadened compared to spin-down states, a consequence of the difference in scattering properties of spin up Fe and V in the bcc structure. This is caused by the fact that the spin-down potential of Fe atoms places the 3d states at similar energy as that of 3d states of V, meaning that spin-down 3d electrons experience an almost perfect lattice without disorder. The exchange splitting of Fe causes the spin-up 3d states to lie considerably below the spin-up states of V, which causes significantly different scattering properties. The CPA method therefore results in more smeared electron states for the spin-up states.

It is also shown that for lower V concentrations, the energy dispersion is reasonably well described in terms of energy bands, with a well-defined dispersion (exemplified by the green shaded bands at and below $E_F$). However, for higher V concentrations (e.g. at 50 %) a clear band dispersion is lacking, at least for some regions of the Brillouin zone. An example of this behavior is noticeable from the energy states along the $\Gamma$-H, $\Gamma$-N and $\Gamma$-P directions, where the 3d electronic states dominate. This is again most noticeable in the green shaded regions at and below $E_F$ becoming much more smeared out.

**Figure 4.** Calculated density of states at the Fermi energy $n(E_F)$ (left y-axis, black open circles) in comparison with the theoretical damping parameter (right y-axis, red filled triangles) as a function of V concentration.
relative to the 30 % V sample indicating that a quasi-particle description of the spin state is no longer possible. As a consequence, the electronic channels that allow for energy dissipation become drastically modified at around 35 % V concentration. It is therefore expected that at around 35 %, the calculated damping and the n(E_f) should not have the same trend as function of V concentration as the data in Fig. 4 explicitly shows.

<table>
<thead>
<tr>
<th>Spin up ↑</th>
<th>Spin down ↓</th>
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<td>(majority)</td>
<td>(minority)</td>
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Figure 5 Spin-polarized Bloch spectral function (BSF) for 30 % V (upper panels) and 50 % V (lower panels) alloys. The color scale is in arbitrary units.

Even with these considerations in mind, the experimental data shows a much more pronounced enhancement of the damping parameter at V concentrations above 35 % V [see Fig. 3(b)], something which may reflect a shortcoming of the CPA description of the electronic structure and damping of this system. In other words, the calculated increase in damping due to the non-quasi-particle behavior of the electron states of the spin-up channel are not adequate enough to describe the much more pronounced increase in the damping found in the experimental data. An alternative explanation for the experimental trend may reside in consideration of the presence of higher crystalline order within the FeV alloy. Indeed, at concentration of 50 % V, the Fe-V system can adopt a fully ordered B2 phase (CsCl structure) where Fe and V occupy different interpenetrating sublattices offset by \((a/2, a/2, a/2)\) where \(a\)
is the simple cubic lattice constant. We refer to this as the fully ordered Fe_{50}V_{50} intermetallic phase. There are naturally intermediate scenarios between these two extremes, which typically is referred to as partial ordering where each sublattice can have a preferential occupation of Fe or V that is in between the completely disordered alloy and the fully ordered intermetallic phase. For the example that we present here, we focus on a partially ordered state where one sublattice has an 80 % preferential occupancy of Fe (i.e., Fe_{80}V_{20}) and the other sublattice has an 80 % preferential occupancy of V (i.e., Fe_{20}V_{80}).

**Figure 6.** Spin-polarized Bloch spectral function (BSF) for 50 % V in B2 structure. Alloy (upper panels) represents random distribution of Fe and V in the two sublattices, partial ordering (middle panels)
outline an 80% preferential occupancy of Fe in one sublattice and the other sublattice has an 80% preferential occupancy of V. In the fully ordered B2 structure (lower panels), Fe and V occupy separate sublattices. The color scale is in arbitrary units.

The calculated damping constants for the fully ordered and partially ordered phases are included in Fig. 3(b). It is immediately apparent that the partial and full order, respectively, increase the calculated damping constant by a factor of ~ 0.6 and ~ 1.5 relative to the disordered alloy, and shows better agreement with the trends in the experimental data. However, XRD did not reveal the additional (001) and (111) reflections that would be expected to appear with B2 order in these samples. However, the scattering factors for Fe and V are very similar owing to their similar atomic numbers. [82] As a result, simulations show the relative intensity of these peaks to that of the (011) peak to be 0.9% and 0.3% respectively. This combined with small signal that results from the polycrystalline structure and broad linewidths renders the (001) and (111) peaks virtually undetectable for our samples with a standard laboratory based x-ray source. As a result, no conclusions can be made about the presence or absence of any B2 order in our samples. The use of resonant XRD at facility based light sources to search for order in this system would be desired in the future.

The microscopic explanation for the increased damping causing by increased ordering is demonstrated via the BSF, plotted for Fe-V alloys with various degrees of order plotted in Fig. 6. Here, it is seen that the partial ordering of Fe and V atoms will influence the electronic structure, and in particular, the width of the BSFs. Comparing the disordered alloys (top panels) and partially ordered alloys (middle panels) bandstructures reveals that ordering sharpens the band features, in particular for the spin up states (the spin down states are sharp for all degrees of partial ordering). The most dramatic effects are found along high symmetry directions of the Brillouin zone, like Γ–R, Γ–M and Γ–X. In the case of full ordering (bottom panels), the BSF is represented by sharp and well-defined bands.

The width of the BSFs greatly influences the damping. Calculations of the damping parameter are often made as a function of this width, and a general trend is that the damping initially decreases with the BSF width, in the regime of intraband scattering, to reach a minimum, whereupon for larger widths, in the regime of inter band scattering, the damping increases again. [83] However, the band broadening comes mainly from the chemical disorder in the present calculations, the trend of the BSFs shown in Fig. 6 can therefore explain, to some extent, why the calculated damping increases with increased order; it is a consequence of the BSFs that become narrower for larger degrees of ordering of Fe and V on the two sublattices. Furthermore, based on these considerations, we offer an explanation of the experimental data shown in Fig.3(b), and in particular, the sharp increase of the damping parameter above 35% V. A partial ordering of Fe and V on the two sublattices, that sets in for V concentrations higher than 35%, would again be consistent with the measured damping parameters.

As a final point, we remark that above we analyzed the electronic structure by means of the BSFs calculated at 0 K. Since Gilbert damping parameters are calculated at finite temperature, for a complete analysis, temperature dependent BSFs would be required, that is not available at present. Here, we fully capture changes in the band structure at the Fermi energy as well as for bands below and above it due to composition variation and ordering. The close lying bands around $E_F$ may be repopulated at elevated temperatures, therefore, changes in the sharpness of the bands below and above $E_F$ due to V doping and ordering are relevant to discuss. An inspection of the Fermi surface alone, done for instance recently in a work by Sipr et al. [84], could miss important changes in bands below and above $E_F$. Finally, our BSF analysis is in line with the above described model presented in Ref. 84, however the additional
band broadening due to the finite temperature is not included. As a consequence, the intra- and interband scattering contribution cannot be quantified either.

**DISCUSSION**

For technological applications, a low intrinsic damping may not be sufficient since the total damping ultimately determines device performance. Thus, it is important to consider the total linewidth that includes extrinsic contributions. A potential dominant contribution to the total linewidth is the inhomogeneous linewidth $\mu_0\Delta H_0$. Inhomogeneity in a film can also translate into device-to-device variations when such a film is patterned into nanosized features. [85] Figure 7 is a plot of $\mu_0\Delta H_0$ versus V concentration. All samples have values below 1.5 mT and with the exception of the pure Fe and 50 % V sample, it is at or below 0.6 mT. These data show sputter deposited films can be produced with minimal extrinsic contribution to the linewidth. In fact, these values are almost an order of magnitude lower than those found in similar epitaxial films measured in the same geometry. [57] However, it is not uncommon for epitaxial systems to have a larger $\mu_0\Delta H_0$, especially when measured in the perpendicular geometry. Despite the difference in $\mu_0\Delta H_0$, comparison of the intrinsic damping parameters between polycrystalline FeV studied here and epitaxial Fe$_{(1-x)}$V$_x$ layers found in Ref. [57] show very little difference as displayed in Fig. 8. Any increase of structural disorder from the polycrystalline films causes only a minimal change of the damping parameter relative to the epitaxial data. This suggests that either the damping mechanism is not strictly intraband or interband scattering alone, or that the spin scattering rates are not dominated by the structural disorder of the system.

![Figure 7](image-url)  
**Figure 7.** Plot of the inhomogeneous linewidth for the 10 nm thick samples versus V concentration.
Figure 8. (a) Comparison of the intrinsic damping between epitaxial films reported in Smith et al. [57] and polycrystalline films as a function of the V concentration. (b) Intrinsic damping of Co-Fe films taken from Schoen et al. [18] and Fe-V films (present work) versus the saturation magnetization. The horizontal line is the intrinsic value for permalloy, Ni$_{80}$Fe$_{20}$.

In Fig. 8(b), we plot the damping parameter versus $\mu_0M_s$ for the Fe-V alloys along with the those of similar Co-Fe alloys found in Ref. [18] that range in composition from 0% Co (pure Fe) to 35% Co (Co$_{35}$Fe$_{65}$). These data demonstrate that exceptionally low values of the damping parameter (< 0.0025) can be maintained over a large range of $\mu_0M_s$ that spans 2.4 T to approximately 0.8 T. Furthermore, these alloys are produced through room temperature sputtering methods that are compatible with CMOS fabrication. It is especially interesting to compare the 35% V sample to Permalloy (Ni$_{80}$Fe$_{20}$), which is one of the most used and studied ferromagnetic metals, especially in the field of spintronics and magnonics. [3] The damping parameter of Ni$_{80}$Fe$_{20}$ is also indicated in Fig. 8(b). At this concentration, $\mu_0M_s$ of both materials is approximately 1 T, but the damping parameter of the Fe$_{65}$V$_{35}$ is
0.0019—a factor of ≈ 2.5 smaller than permalloy. [86] For applications in magnonics, lower damping is desired since the lifetime of a spin excitation is increased with lower damping. From a damping perspective, this suggests that Fe-V is a suitable replacement for permalloy for some applications. Of course, permalloy also possesses other desirable qualities such as vanishing magnetostriction. However, in the case of FeV, the magnetostriction has a zero crossing at approximately 5-8 % V, but the amplitude of the saturation magnetostriction was found to be relatively low at < 12 ppm over the range of concentrations studied here. [87–89]

SUMMARY

In summary, we have measured the intrinsic damping parameter in polycrystalline, sputter-deposited Fe-V alloys that span the range from pure Fe to 50 % V in atomic concentration. The intrinsic damping shows a minimum value of \( (1.53 \pm 0.08) \times 10^{-3} \) at approximately 20 % V. Extremely low values of the damping parameter are found for alloys with a concentration at or below 35 % V. Above this concentration, there is a larger increase in the damping as the V content is increased. In addition, the saturation magnetization is confirmed to continuously vary as predicted from the Slater-Pauling model. Ab initio calculations qualitatively reproduce the trends in the damping parameter. However, for the alloys with more than 35 % V, some degree of partial B2 order is needed to describe the increase in the damping found in the experimental data. This increase in damping for higher V content is explained through sharpening of the majority Bloch spectral functions, as more B2 order is introduced.

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